

UTC UNISONIC TECHNOLOGIES CO., LTD

7N10

Power MOSFET

7.0A, 100V N-CHANNEL **POWER MOSFET**

DESCRIPTION

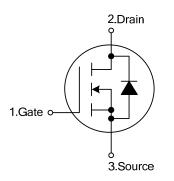
The UTC 7N10 is an N-Channel enhancement mode power MOSFET, providing customers with excellent switching performance and minimum on-state resistance. The UTC 7N10 uses planar stripe and DMOS technology to provide perfect quality. This device can also withstand high energy pulse in the avalanche and the commutation mode.

The UTC 7N10 is generally applied in low voltage applications, such as DC motor controls, audio amplifiers and high efficiency switching DC/DC converters.

FEATURES

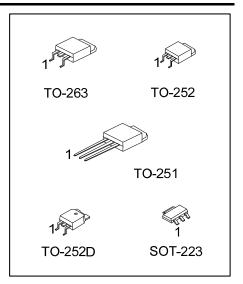
- * $R_{DS(ON)} \le 0.35 \ \Omega \ @ V_{GS} = 10V, \ I_D = 3.5A$
- * Fast Switching
- * Improved dv/dt Capability

SYMBOL



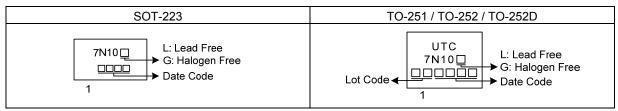
ORDERING INFORMATION

| Ordering Number | | Deelvere | Pin Assignment | | | Dealving | |
|---|-------------------------|----------|----------------|---|---|-----------|--|
| Lead Free | Halogen Free | Package | 1 | 2 | 3 | Packing | |
| 7N10L-AA3-R | 7N10L-AA3-R 7N10G-AA3-R | | G | D | S | Tape Reel | |
| 7N10L-TM3-T | 7N10L-TM3-T 7N10G-TM3-T | | G | D | S | Tube | |
| 7N10L-TN3-R | 7N10L-TN3-R 7N10G-TN3-R | | G | D | S | Tape Reel | |
| 7N10L-TND-R | 7N10G-TND-R | TO-252D | G | D | S | Tape Reel | |
| 7N10L-TQ2-T | 7N10G-TQ2-T | TO-263 | G | D | S | Tube | |
| 7N10L-TQ2-R | 7N10G-TQ2-R | TO-263 | G | D | S | Tape Reel | |
| Note: Pin Assignment: G: Ga | | | | | | | |
| 7N10G-AA3-R (1)Packing Type (2)Package Type (2)Package Type (3)Green Package (3)Green Package | | | | | | | |



7N10

MARKING





■ ABSOLUTE MAXIMUM RATINGS (T_c=25°C, unless otherwise specified)

| PARAMETER | | SYMBOL | RATINGS | UNIT |
|---|--------------------------|------------------|------------|------|
| Drain -Source Voltage | | V _{DSS} | 100 | V |
| Gate-Source Voltage | | V _{GSS} | ±25 | V |
| Continuous Drain Current | | I _D | 7 | А |
| Pulsed Drain Current (Note 2) | | I _{DM} | 14 | А |
| Single Pulsed Avalanche Energy (Note 3) | | E _{AS} | 117 | mJ |
| Peak Diode Recovery dv/dt (Note 4) | | dv/dt | 6.0 | V/ns |
| Power Dissipation | SOT-223 | | 2.5 | W |
| | TO-251/TO-252 TO-252D | P _D | 32 | W |
| | TO-263 | | 55 | W |
| Operating Junction Temperature | | TJ | -55 ~ +150 | °C |
| Storage Temperature | | T _{STG} | -55 ~ +150 | °C |

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating : Pulse width limited by maximum junction temperature

3. L =30mH, I_{AS} =2.8A, V_{DD} =25V, R_G =25 Ω Starting T_J =25°C

4. $I_{SD} \le 7.0A$, di/dt $\le 300A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25^{\circ}C$

THERMAL DATA

| PARAMETER | | SYMBOL | RATINGS | UNIT |
|---------------------|--------------------------|-----------------|---------|------|
| Junction to Ambient | SOT-223 | | 140 | °C/W |
| | TO-251/TO-252 TO-252D | θ _{JA} | 110 | °C/W |
| | TO-263 | | 62.5 | °C/W |
| Junction to Case | SOT-223 | | 50 | °C/W |
| | TO-251/TO-252 TO-252D | θ_{Jc} | 3.9 | °C/W |
| | TO-263 | | 2.27 | °C/W |

Note: When mounted on the minimum pad size recommended (PCB Mount).



■ ELECTRICAL CHARACTERISTICS (T_c=25°C, unless otherwise specified)

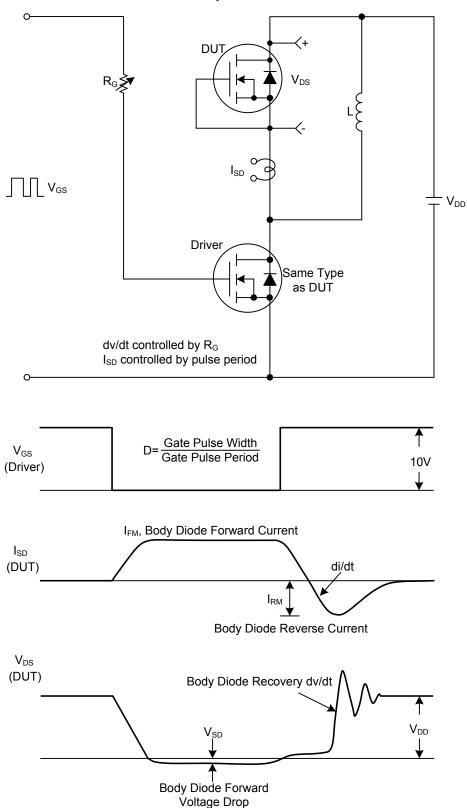
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------------------------|---------------------|--|-----|-------|------|------|
| OFF CHARACTERISTICS | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =250μA | 100 | | | V |
| Drain Course Lookage Current | I _{DSS} | V _{DS} =100V, V _{GS} =0V | | | 1 | μA |
| Drain-Source Leakage Current | | V _{DS} =80V, T _C =125°C | | | 10 | μA |
| Gate-Source Leakage Current | I _{GSS} | V_{GS} =±25V, V_{DS} =0V | | | ±100 | nA |
| ON CHARACTERISTICS | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | V _{DS} = V _{GS} , I _D =250μA | 2.0 | | 4.0 | V |
| Static Drain-Source On-Resistance | R _{DS(ON)} | V _{GS} =10V, I _D =3.5A | | 0.144 | 0.35 | Ω |
| DYNAMIC PARAMETERS | | | | | | |
| Input Capacitance | CISS | | | 370 | | pF |
| Output Capacitance | C _{OSS} | V _{DS} =25V, V _{GS} =0V, f=1.0MHz | | 70 | | pF |
| Reverse Transfer Capacitance | C _{RSS} | | | 9 | | pF |
| SWITCHING PARAMETERS | | | | | | |
| Total Gate Charge | Q_{G} | | | 13.5 | | nC |
| Gate Source Charge | Q _{GS} | −V _{DS} =80V, V _{GS} =10V, I _D =7.0A, −I _G =1mA (Note 1, 2) | | 5 | | nC |
| Gate Drain Charge | Q_{GD} | | | 2.3 | | nC |
| Turn-ON Delay Time | t _{D(ON)} | | | 5 | | ns |
| Turn-ON Rise Time | t _R | V _{DD} =50V, V _{GS} =10V, I _D =7.0A, | | 16 | | ns |
| Turn-OFF Delay Time | t _{D(OFF)} | R _G =25Ω (Note 1, 2) | | 20 | | ns |
| Turn-OFF Fall-Time | t _F | | | 18 | | ns |
| SOURCE- DRAIN DIODE RATINGS AND C | HARACTERI | STICS | | | | |
| Maximum Continuous Drain-Source Diode | | | | | 7 | А |
| Forward Current | I _S | | | | 1 | A |
| Maximum Pulsed Drain-Source Diode | L. | | | | 14 | А |
| Forward Current | I _{SM} | | | | 14 | А |
| Drain-Source Diode Forward Voltage | V_{SD} | I _S =7A, V _{GS} =0V | | | 1.5 | V |
| Reverse Recovery Time | t _{rr} | V _{GS} =0V, I _S =7.3A, | | 71 | | ns |
| Reverse Recovery Charge | Q _{rr} | di _F /dt=100A/µs 304 | | | | nC |

Notes: 1. Pulse Test: Pulse width \leq 300µs, Duty cycle \leq 2%.

2. Essentially independent of operating temperature.



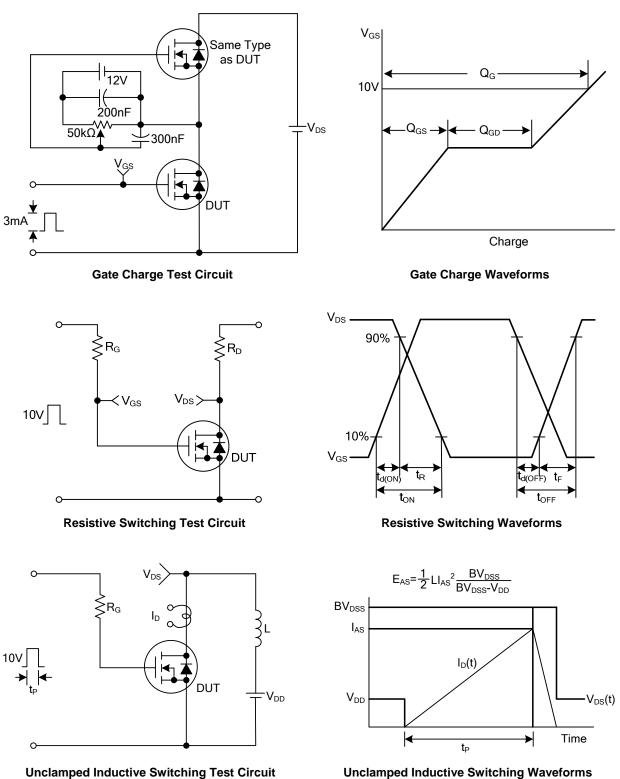
TEST CIRCUITS AND WAVEFORMS



Peak Diode Recovery dv/dt Test Circuit & Waveforms



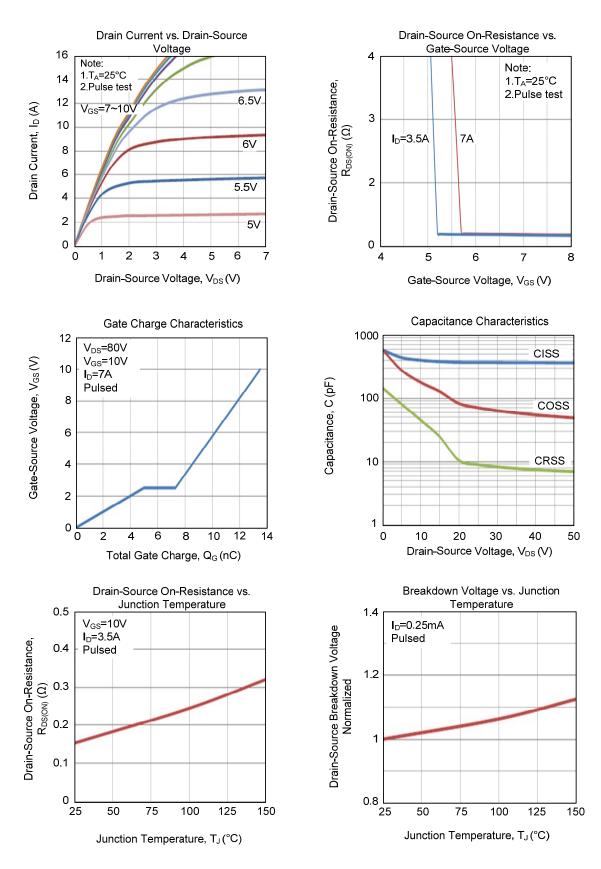
TEST CIRCUITS AND WAVEFORMS



Unclamped Inductive Switching Waveforms

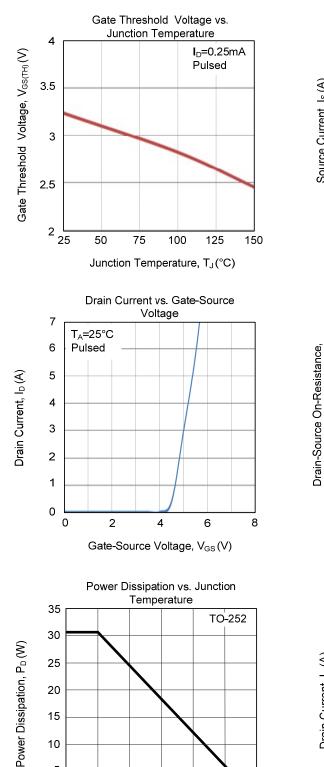


TYPICAL CHARACTERISTICS

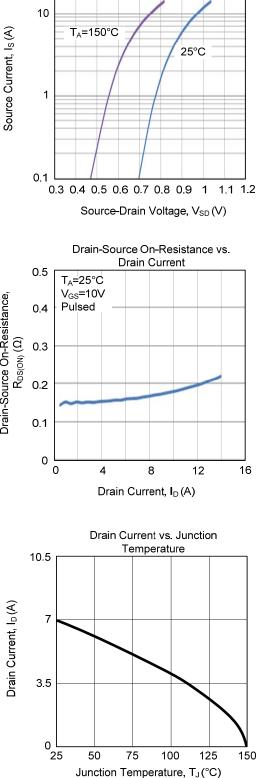


Source Current vs. Source-Drain

Voltage



TYPICAL CHARACTERISTICS (Cont.)





50

75

Junction Temperature, T_J (°C)

100

125

150

20 15

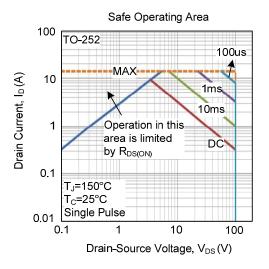
10 5

0

0

25





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